



# MASINDE MULIRO UNIVERSITY OF SCIENCE AND TECHNOLOGY (MMUST)

#### UNIVERSITY EXAMINATIONS 2021/2022 ACADEMIC YEAR

### FIRST YEAR SECOND SEMESTER SPECIAL/SUPPLEMENTARY EXAMINATIONS

## FOR THE DEGREE OF DOCTOR OF PHILOSOPHY IN PHYSICS

COURSE CODE:

**SPH924E** 

COURSE TITLE: PHYSICS AND APPLICATIONS
SEMICONDUCTOR
NANOSTRUCTURES

**DATE**: THURSDAY 4<sup>TH</sup> AUGUST, 2022

**TIME**: 2 PM - 5 PM

**INSTRUCTIONS TO CANDIDATES** 

TIME: 3 Hours

Answer Five Questions.

Symbols used bear the usual meaning.

MMUST observes ZERO tolerance to examination cheating

This Paper Consists of 2 Printed Pages. Please Turn Over.



#### **QUESTION ONE (14 MARKS)**

- 1a) Heterostructures are semiconductor structures in which chemical composition changes with position, represent (i) Schematic illustration of a quantum well, (ii) representation of the energy barriers and the first three confined wave-functions, (iii) Energy dispersion for n = 1,2,3 as a function of  $k_{\parallel}$ , the wave vector perpendicular to the confining direction. (iv) Density of states as a function of the energy (12 marks)
- 1b) Show the energy dispersion relation for electrons in a quantum well

(2 marks)

#### **QUESTION TWO (14 MARKS)**

Discuss the density of states for three, two, one and zero dimensional system structures
(14 marks)

#### **QUESTION THREE (14 MARKS)**

Discuss the synthesis of the following varieties of quantum dots namely (i) Lithographically defined quantum dots (ii) Epitaxially self-assembled quantum dots (iii) colloidal quantum dots (14 marks)

#### **QUESTION FOUR (14 MARKS)**

Using the quantum mechanical approach estimate the size dependent energy gap of a spherical semiconductor quantum dot (14 marks)

#### **OUESTION FIVE (14 MARKS)**

Determine the electron wave function for an electron entering a multiple quantum well hence show the electron transition mechanisms (14 marks)

#### **QUESTION SIX (14 MARKS)**

Using Drude classical model of the magnetoresistance in semiconductors Derive the quantum Hall effect parameters for a semiconductor nanostructure (14 marks)